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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

Freescale Semiconductor
Technical Data

Document Number: MPC8260EC
Rev. 2, 05/2010

MPC8260 PowerQUICC II Integrated Communications Processor Hardware Specifications

This document contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications for the .29 µm (HiP3) devices of the PowerQUICC II family of communications processors: the MPC8260 and the MPC8255. Throughout this document, the MPC8260 and the MPC8255 are collectively referred to as the MPC8260.

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Figure 1 shows the block diagram for the MPC8260.

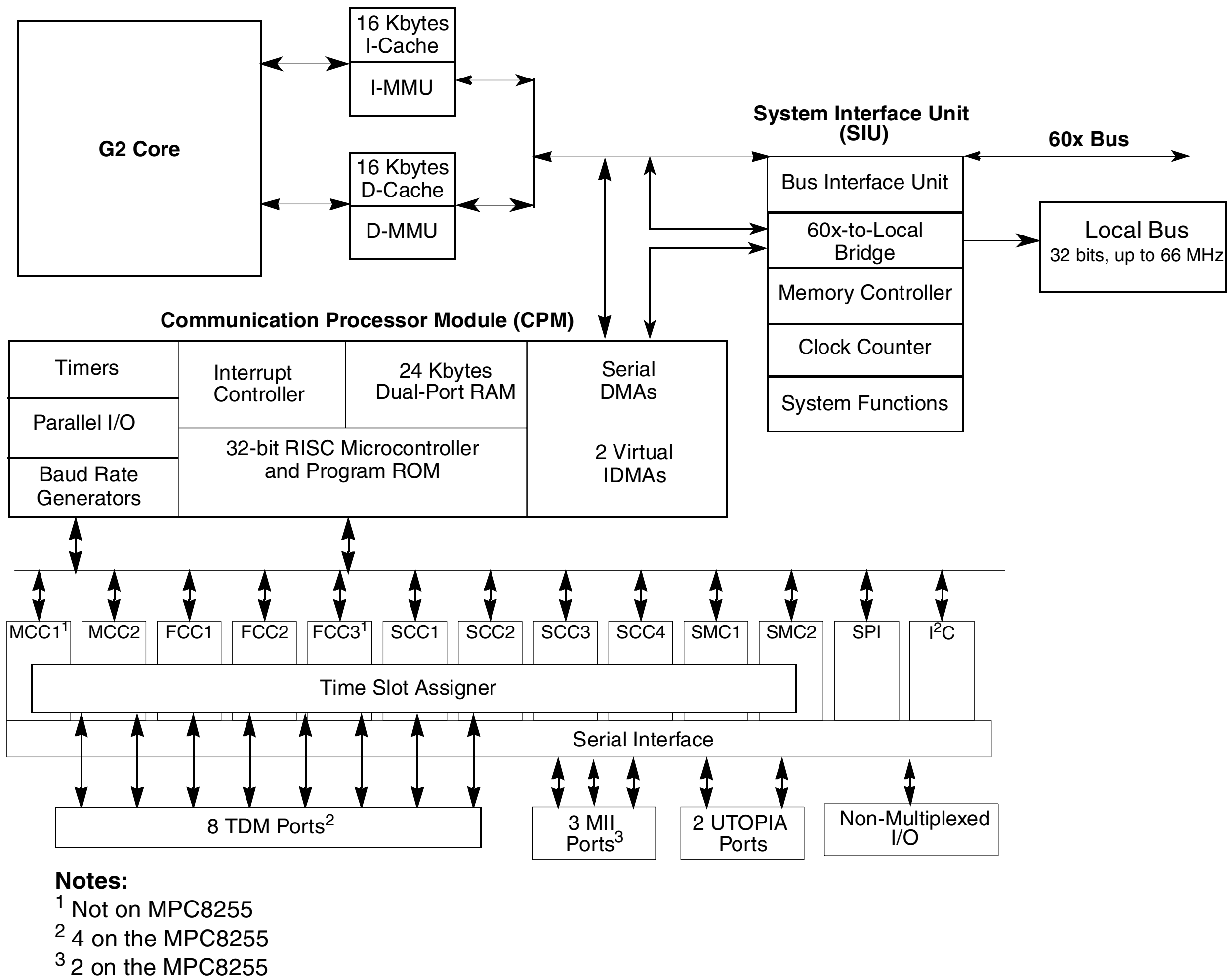


Figure 1. MPC8260 Block Diagram

1 Features

The major features of the MPC8260 are as follows:

- Dual-issue integer core
  - — A core version of the EC603e microprocessor
  - — System core microprocessor supporting frequencies of 133–200 MHz (150–200 MHz for the MPC8255)
  - — Separate 16-Kbyte data and instruction caches:
    - – Four-way set associative
    - – Physically addressed
    - – LRU replacement algorithm
  - — PowerPC architecture-compliant memory management unit (MMU)

- — Common on-chip processor (COP) test interface
- — High-performance (4.4–5.1 SPEC95 benchmark at 200 MHz; 280 Dhrystones MIPS at 200 MHz)
- — Supports bus snooping for data cache coherency
- — Floating-point unit (FPU)

- Separate power supply for internal logic and for I/O
- Separate PLLs for G2 core and for the CPM
  - — G2 core and CPM can run at different frequencies for power/performance optimization
  - — Internal core/bus clock multiplier that provides 1.5:1, 2:1, 2.5:1, 3:1, 3.5:1, 4:1, 5:1, 6:1 ratios
  - — Internal CPM/bus clock multiplier that provides 2:1, 2.5:1, 3:1, 3.5:1, 4:1, 5:1, 6:1 ratios
- 64-bit data and 32-bit address 60x bus
  - — Bus supports multiple master designs
  - — Supports single- and four-beat burst transfers
  - — 64-, 32-, 16-, and 8-bit port sizes controlled by on-chip memory controller
  - — Supports data parity or ECC and address parity
- 32-bit data and 18-bit address local bus
  - — Single-master bus, supports external slaves
  - — Eight-beat burst transfers
  - — 32-, 16-, and 8-bit port sizes controlled by on-chip memory controller
- System interface unit (SIU)
  - — Clock synthesizer
  - — Reset controller
  - — Real-time clock (RTC) register
  - — Periodic interrupt timer
  - — Hardware bus monitor and software watchdog timer
  - — IEEE Std 1149.1™ JTAG test access port
- Twelve-bank memory controller
  - — Glueless interface to SRAM, page mode SDRAM, DRAM, EPROM, Flash and other user-definable peripherals
  - — Byte write enables and selectable parity generation
  - — 32-bit address decodes with programmable bank size
  - — Three user programmable machines, general-purpose chip-select machine, and page-mode pipeline SDRAM machine
  - — Byte selects for 64 bus width (60x) and byte selects for 32 bus width (local)
  - — Dedicated interface logic for SDRAM
- CPU core can be disabled and the device can be used in slave mode to an external core
- Communications processor module (CPM)

- Embedded 32-bit communications processor (CP) uses a RISC architecture for flexible support for communications protocols
- Interfaces to G2 core through on-chip 24-Kbyte dual-port RAM and DMA controller
- Serial DMA channels for receive and transmit on all serial channels
- Parallel I/O registers with open-drain and interrupt capability
- Virtual DMA functionality executing memory-to-memory and memory-to-I/O transfers
- Three fast communications controllers (two on the MPC8255) supporting the following protocols:
  - 10/100-Mbit Ethernet/IEEE Std 802.3™ CDMA/CS interface through media independent interface (MII)
  - ATM—Full-duplex SAR protocols at 155 Mbps, through UTOPIA interface, AAL5, AAL1, AAL0 protocols, TM 4.0 CBR, VBR, UBR, ABR traffic types, up to 16 K external connections
  - Transparent
  - HDLC—Up to T3 rates (clear channel)
- Two multichannel controllers (MCCs) (only MCC2 on the MPC8255)
  - Each MCC handles 128 serial, full-duplex, 64-Kbps data channels. Each MCC can be split into four subgroups of 32 channels each.
  - Almost any combination of subgroups can be multiplexed to single or multiple TDM interfaces up to four TDM interfaces per MCC
- Four serial communications controllers (SCCs) identical to those on the MPC860, supporting the digital portions of the following protocols:
  - Ethernet/IEEE 802.3 CDMA/CS
  - HDLC/SDLC and HDLC bus
  - Universal asynchronous receiver transmitter (UART)
  - Synchronous UART
  - Binary synchronous (BISYNC) communications
  - Transparent
- Two serial management controllers (SMCs), identical to those of the MPC860
  - Provide management for BRI devices as general circuit interface (GCI) controllers in time-division-multiplexed (TDM) channels
  - Transparent
  - UART (low-speed operation)
- One serial peripheral interface identical to the MPC860 SPI
- One inter-integrated circuit (I^2C) controller (identical to the MPC860 I^2C controller)
  - Microwire compatible
  - Multiple-master, single-master, and slave modes

- Up to eight TDM interfaces (4 on the MPC8255)
  - Supports two groups of four TDM channels for a total of eight TDMs
  - 2,048 bytes of SI RAM
  - Bit or byte resolution
  - Independent transmit and receive routing, frame synchronization
  - Supports T1, CEPT, T1/E1, T3/E3, pulse code modulation highway, ISDN basic rate, ISDN primary rate, Freescale interchip digital link (IDL), general circuit interface (GCI), and user-defined TDM serial interfaces
- Eight independent baud rate generators and 20 input clock pins for supplying clocks to FCCs, SCCs, SMCs, and serial channels
- Four independent 16-bit timers that can be interconnected as two 32-bit timers

2 Electrical and Thermal Characteristics

This section provides AC and DC electrical specifications and thermal characteristics for the MPC8260.

2.1 DC Electrical Characteristics

This section describes the DC electrical characteristics for the MPC8260. Table 1 shows the maximum electrical ratings.

Table 1. Absolute Maximum Ratings[1]

Rating	Symbol	Value	Unit
Core supply voltage[2]	VDD	-0.3 – 2.75	V
PLL supply voltage[2]	VCCSYN	-0.3 – 2.75	V
I/O supply voltage[3]	VDDH	-0.3 – 4.0	V
Input voltage[4]	VIN	GND(-0.3) – 3.6	V
Junction temperature	T_j	120	°C
Storage temperature range	T_{STG}	(-55) – (+150)	°C

Note:

1 Absolute maximum ratings are stress ratings only; functional operation (see Table 2) at the maximums is not guaranteed. Stress beyond those listed may affect device reliability or cause permanent damage.

2 **Caution:** VDD/VCCSYN must not exceed VDDH by more than 0.4 V at any time, including during power-on reset.

3 **Caution:** VDDH can exceed VDD/VCCSYN by 3.3 V during power on reset by no more than 100 mSec. VDDH should not exceed VDD/VCCSYN by more than 2.0 V during normal operation.

4 **Caution:** VIN must not exceed VDDH by more than 2.5 V at any time, including during power-on reset.

Table 2 lists recommended operational voltage conditions.

Table 2. Recommended Operating Conditions[1]

Rating	Symbol	2.5-V Device[2]	Unit
Core supply voltage	VDD	2.4–2.7	V
PLL supply voltage	VCCSYN	2.4–2.7	V
I/O supply voltage	VDDH	3.135 – 3.465	V
Input voltage	VIN	GND (-0.3) – 3.465	V
Junction temperature (maximum)	T_j	105	°C

[1] **Caution:** These are the recommended and tested operating conditions. Proper device operating outside of these conditions is not guaranteed.

[2] Parts labeled with an “-HVA” suffix are 2.6-V devices.

NOTE: Core, PLL, and I/O Supply Voltages

VDDH, VCCSYN, and VDD must track each other and both must vary in the same direction—in the positive direction (+5% and +0.1 Vdc) or in the negative direction (–5% and –0.1 Vdc).

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (either GND or V_{CC}).

Figure 2 shows the undershoot and overshoot voltage of the 60x and local bus memory interface of the MPC8280. Note that in PCI mode the I/O interface is different.

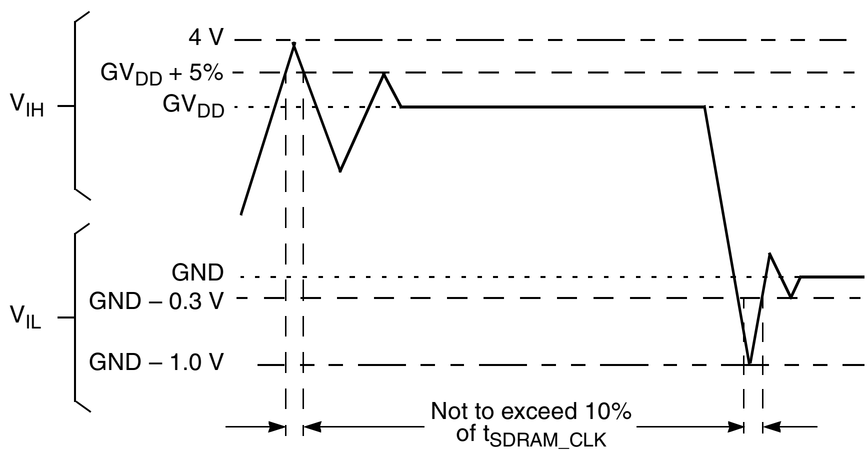


Figure 2. Overshoot/Undershoot Voltage

Table 3 shows DC electrical characteristics.

Table 3. DC Electrical Characteristics[1]

Characteristic	Symbol	Min	Max	Unit
Input high voltage, all inputs except CLKIN	V_{IH}	2.0	3.465	V
Input low voltage	V_{IL}	GND	0.8	V
CLKIN input high voltage	V_{IHC}	2.4	3.465	V
CLKIN input low voltage	V_{ILC}	GND	0.4	V
Input leakage current, V_{IN} = VDDH[2]	I_{IN}	—	10	µA
Hi-Z (off state) leakage current, V_{IN} = VDDH[2]	I_{OZ}	—	10	µA
Signal low input current, V_{IL} = 0.8 V	I_L	—	1	µA
Signal high input current, V_{IH} = 2.0 V	I_H	—	1	µA
Output high voltage, I_{OH} = –2 mA except XFC, UTOPIA mode, and open drain pins In UTOPIA mode: I_{OH} = -8.0mA PA[0-31] PB[4-31] PC[0-31] PD[4-31]	V_{OH}	2.4	—	V
In UTOPIA mode: I_{OL} = 8.0mA PA[0-31] PB[4-31] PC[0-31] PD[4-31]	V_{OL}	—	0.5	V

Table 3. DC Electrical Characteristics[1] (continued)

Characteristic	Symbol	Min	Max	Unit
I_{OL} = 7.0mA BR BG ABB/IRQ2 TS A[0-31] TT[0-4] TBST TSIZE[0–3] AACK ARTRY DBG DBB/IRQ3 D[0-63] DP(0)/RSRV/EXT_BR2 DP(1)/IRQ1/EXT_BG2 DP(2)/TLBISYNC/IRQ2/EXT_DBG2 DP(3)/IRQ3/EXT_BR3/CKSTP_OUT DP(4)/IRQ4/EXT_BG3/CORE_SREST DP(5)/TBEN/IRQ5/EXT_DBG3 DP(6)/CSE(0)/IRQ6 DP(7)/CSE(1)/IRQ7 PSDVAL TA TEA GBL/IRQ1 CI/BADDR29/IRQ2 WT/BADDR30/IRQ3 L2_HIT/IRQ4 CPU_BG/BADDR31/IRQ5 CPU_DBG CPU_BR IRQ0/NMI_OUT IRQ7/INT_OUT/APE PORESET HRESET SRESET RSTCONF QREQ	V_{OL}	—	0.4	V

Table 3. DC Electrical Characteristics[1] (continued)

Characteristic	Symbol	Min	Max	Unit
I_{OL} = 5.3mA CS[0-9] CS(10)/BCTL1 CS(11)/AP(0) BADDR[27–28] ALE BCTL0 PWE(0:7)/PSDDQM(0:7)/PBS(0:7) PSDA10/PGPL0 PSDWE/PGPL1 POE/PSDRAS/PGPL2 PSDCAS/PGPL3 PGTA/PUPMWAIT/PGPL4/PPBS PSDAMUX/PGPL5 LWE[0–3]LSDDQM[0:3]/LBS[0–3] LSDA10/LGPL0 LSDWE/LGPL1 LOE/LSDRAS/LGPL2 LSDCAS/LGPL3 LGTA/LUPMWAIT/LGPL4/LPBS LSDAMUX[3]/LGPL5 LWR MODCK1/AP(1)/TC(0)/BNKSEL(0) MODCK2/AP(2)/TC(1)/BNKSEL(1) MODCK3/AP(3)/TC(2)/BNKSEL(2) I_{OL} = 3.2mA L_A14 L_A15/SMI L_A16 L_A17/CKSTP_OUT L_A18 L_A19 L_A20 L_A21 L_A22 L_A23 L_A24 L_A25 L_A26 L_A27 L_A28/CORE_SRESET L_A29 L_A30 L_A31 LCL_D(0-31) LCL_DP(0-3) PA[0–31] PB[4–31] PC[0–31] PD[4–31] TDO	V_{OL}	—	0.4	V

1 The default configuration of the CPM pins (PA[0–31], PB[4–31], PC[0–31], PD[4–31]) is input. To prevent excessive DC current, it is recommended to either pull unused pins to GND or VDDH, or to configure them as outputs.

2 The leakage current is measured for nominal VDD, VCCSYN, and VDD.

[3] Rev C.2 silicon only.

2.2 Thermal Characteristics

Table 4 describes thermal characteristics.

Table 4. Thermal Characteristics

Characteristics	Symbol	Value	Unit	Air Flow
Thermal resistance for TBGA	θ_{JA}	13.07[1]	°C/W	NC[2]
	θ_{JA}	9.55[1]	°C/W	1 m/s
	θ_{JA}	10.48[3]	°C/W	NC
	θ_{JA}	7.78[3]	°C/W	1 m/s

Note:

[1] Assumes a single layer board with no thermal vias
[2] Natural convection
[3] Assumes a four layer board

2.3 Power Considerations

The average chip-junction temperature, T_J, in °C can be obtained from the following:

$$T_J = T_A + (P_D \times \theta_{JA}) \quad (1)$$

where

T_A = ambient temperature °C

θ_{JA} = package thermal resistance, junction to ambient, °C/W

$P_D = P_{INT} + P_{I/O}$

$P_{INT} = I_{DD} \times V_{DD}$ Watts (chip internal power)

$P_{I/O}$ = power dissipation on input and output pins (determined by user)

For most applications $P_{I/O} < 0.3 \times P_{INT}$. If $P_{I/O}$ is neglected, an approximate relationship between P_D and T_J is the following:

$$P_D = K/(T_J + 273° C) \quad (2)$$

Solving equations (1) and (2) for K gives:

$$K = P_D \times (T_A + 273° C) + \theta_{JA} \times P_D^2 \quad (3)$$

where K is a constant pertaining to the particular part. K can be determined from equation (3) by measuring P_D (at equilibrium) for a known T_A. Using this value of K, the values of P_D and T_J can be obtained by solving equations (1) and (2) iteratively for any value of T_A.

2.3.1 Layout Practices

Each V_{CC} pin should be provided with a low-impedance path to the board's power supply. Each ground pin should likewise be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on chip. The V_{CC} power supply should be bypassed to ground using at least four 0.1 µF by-pass capacitors located as close as possible to the four sides of the package. The capacitor leads and associated printed circuit traces connecting to chip V_{CC} and ground should be kept to less than half an inch per capacitor lead. A four-layer board is recommended, employing two inner layers as V_{CC} and GND planes.

All output pins on the MPC8260 have fast rise and fall times. Printed circuit (PC) trace interconnection length should be minimized in order to minimize overdamped conditions and reflections caused by these fast output switching times. This recommendation particularly applies to the address and data buses. Maximum PC trace lengths of six inches are recommended. Capacitance calculations should consider all device loads as well as parasitic capacitances due to the PC traces. Attention to proper PCB layout and bypassing becomes especially critical in systems with higher capacitive loads because these loads create higher transient currents in the V_{CC} and GND circuits. Pull up all unused inputs or signals that will be inputs during reset. Special care should be taken to minimize the noise levels on the PLL supply pins.

Table 5 provides preliminary, estimated power dissipation for various configurations. Note that suitable thermal management is required for conditions above P_D = 3W (when the ambient temperature is 70° C or greater) to ensure the junction temperature does not exceed the maximum specified value. Also note that the I/O power should be included when determining whether to use a heat sink.

Table 5. Estimated Power Dissipation for Various Configurations[1]

Bus (MHz)	CPM Multiplier	CPU Multiplier	CPM (MHz)	CPU (MHz)	P_{INT} (W)[2]				
					Vddl				
					2.4	2.5	2.6	2.7	2.8[3]
33.3	4	4	133.3	133.3	2.04	2.14	2.26	2.38	2.50
50.0	2	3	100	150.0	2.21	2.30	2.45	2.59	2.69
66.7	2	2.5	133.3	166.7	2.47	2.62	2.74	2.88	3.02
66.7	2.5	2.5	166.7	166.7	2.57	2.69	2.83	2.98	3.12
66.7	2	3	133.3	200.0	2.81	2.95	3.12	3.29	3.43
66.7	2.5	3	166.7	200.0	2.88	3.05	3.22	3.38	3.55
50.0	3	4	150	200.0	2.83	3.00	3.14	3.31	3.48

Note:

1 Test temperature = room temperature (25° C)
2 $P_{INT} = I_{DD} \times V_{DD}$ Watts
3 2.8 Vddl does not apply to HiP3 Rev C silicon.

2.4 AC Electrical Characteristics

The following sections include illustrations and tables of clock diagrams, signals, and CPM outputs and inputs for the 66 MHz MPC8260 device. Note that AC timings are based on a 50-p*f* load. Typical output buffer impedances are shown in Table 6.

Table 6. Output Buffer Impedances[1]

Output Buffers	Typical Impedance (Ω)
60x bus	40
Local bus	40
Memory controller	40
Parallel I/O	46

Note:

[1] These are typical values at 65° C. The impedance may vary by ±25% with process and temperature.

Table 7 lists CPM output characteristics.

Table 7. AC Characteristics for CPM Outputs[1]

Spec Number		Characteristic	Max Delay (ns)	Min Delay (ns)
Max	Min		66 MHz	66 MHz
sp36a	sp37a	FCC outputs—internal clock (NMSI)	6	1
sp36b	sp37b	FCC outputs—external clock (NMSI)	14	2
sp40	sp41	TDM outputs/SI	25	5
sp38a	sp39a	SCC/SMC/SPI/I2C outputs—internal clock (NMSI)	19	1
sp38b	sp39b	Ex_SCC/SMC/SPI/I2C outputs—external clock (NMSI)	19	2
sp42	sp43	PIO/TIMER/IDMA outputs	14	1

Note:

[1] Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.

Table 8 lists CPM input characteristics.

NOTE: Rise/Fall Time on CPM Input Pins

It is recommended that the rise/fall time on CPM input pins should not exceed 5 ns. This should be enforced especially on clock signals. Rise time refers to signal transitions from 10% to 90% of VCC; fall time refers to transitions from 90% to 10% of VCC.

Table 8. AC Characteristics for CPM Inputs[1]

Spec Number		Characteristic	Setup (ns)	Hold (ns)
Setup	Hold		66 MHz	66 MHz
sp16a	sp17a	FCC inputs—internal clock (NMSI)	10	0
sp16b	sp17b	FCC inputs—external clock (NMSI)	3	3
sp20	sp21	TDM inputs/SI	15	12
sp18a	sp19a	SCC/SMC/SPI/I2C inputs—internal clock (NMSI)	20	0
sp18b	sp19b	SCC/SMC/SPI/I2C inputs—external clock (NMSI)	5	5
sp22	sp23	PIO/TIMER/IDMA inputs	10	3

Note:

1 Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.

Note that although the specifications generally reference the rising edge of the clock, the following AC timing diagrams also apply when the falling edge is the active edge.

Figure 3 shows the FCC external clock.

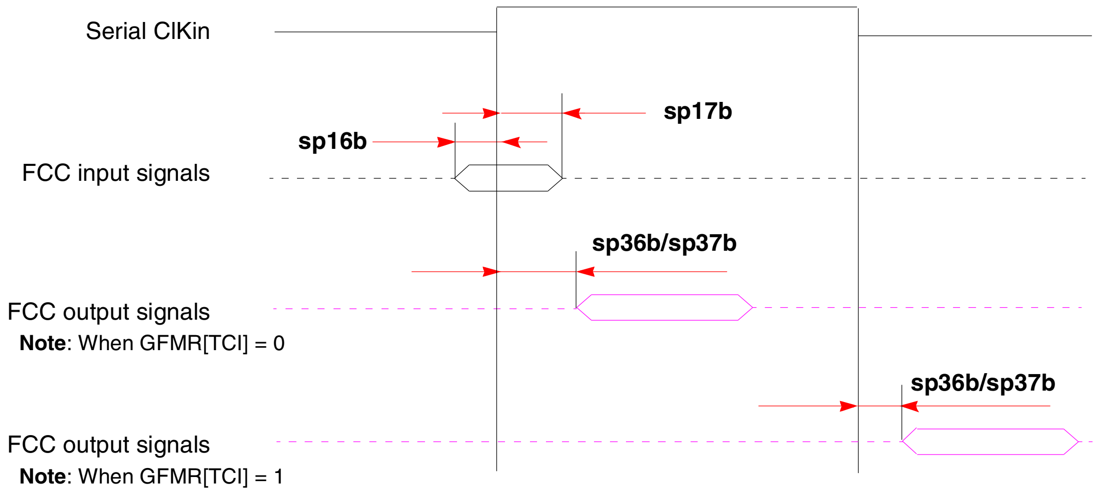


Figure 3. FCC External Clock Diagram

Figure 4 shows the FCC internal clock.

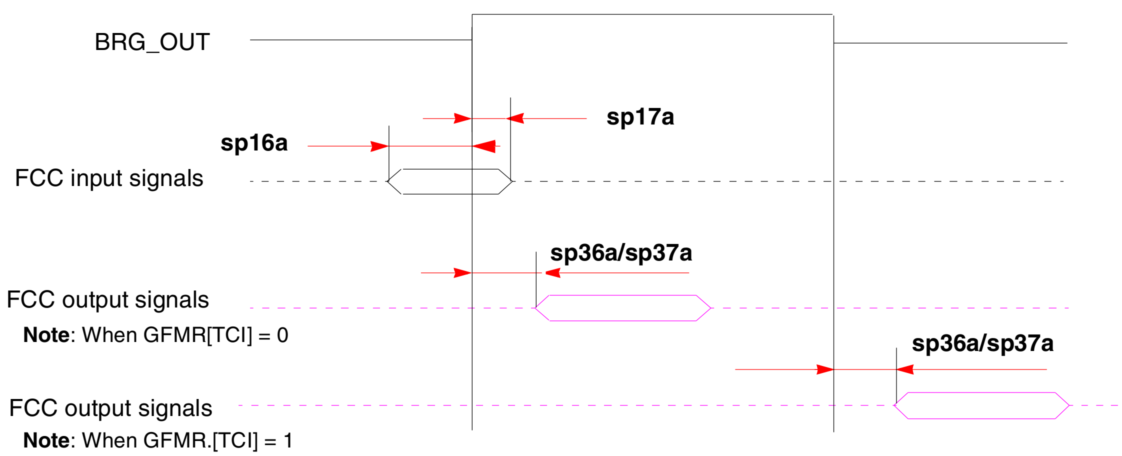


Figure 4. FCC Internal Clock Diagram

Figure 5 shows the SCC/SMC/SPI/I^{2}C external clock.

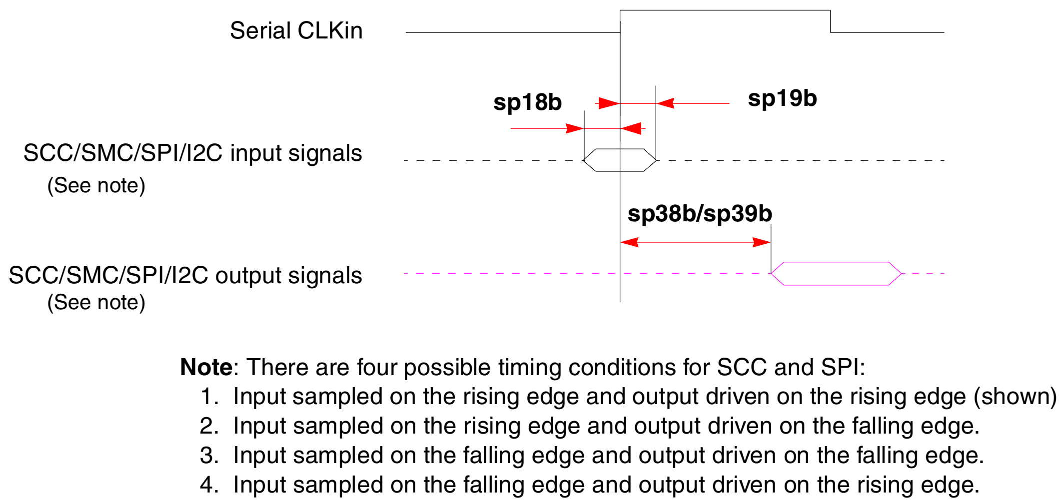


Figure 5. SCC/SMC/SPI/I^{2}C External Clock Diagram

Figure 6 shows the SCC/SMC/SPI/I^{2}C internal clock.

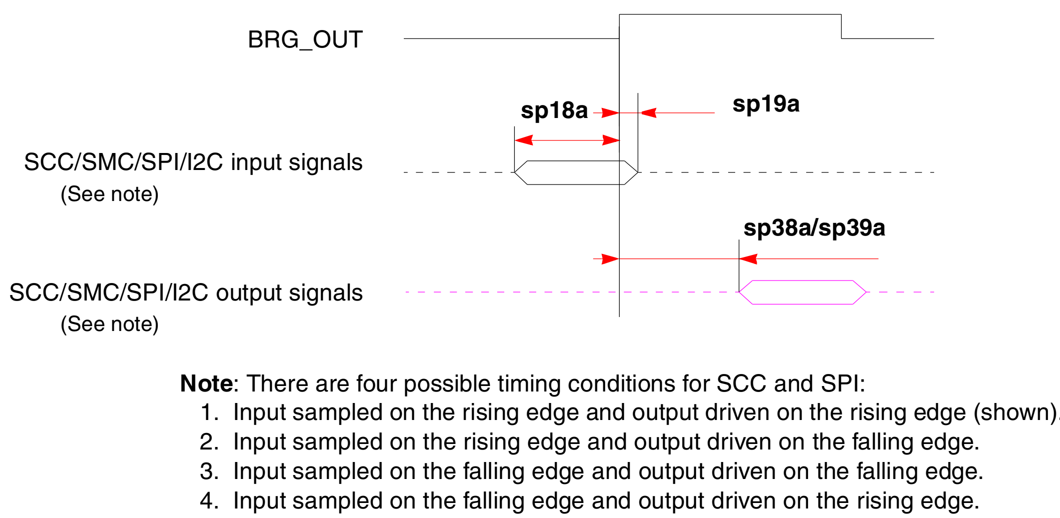


Figure 6. SCC/SMC/SPI/I^{2}C Internal Clock Diagram

Figure 7 shows PIO, timer, and DMA signals.

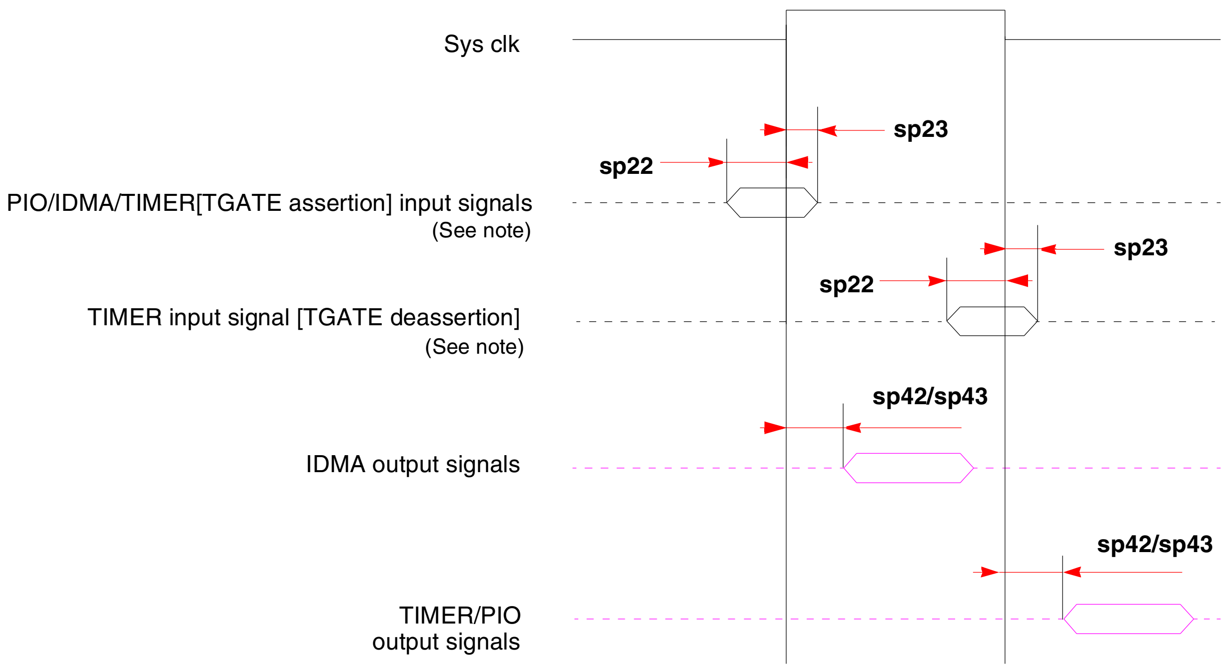


Figure 7. PIO, Timer, and DMA Signal Diagram

Table 9 lists SIU input characteristics.

Table 9. AC Characteristics for SIU Inputs[1]

Spec Number		Characteristic	Setup (ns)	Hold (ns)
Setup	Hold		66 MHz	66 MHz
sp11	sp10	$\overline{\text{AACK}}$/$\overline{\text{ARTRY}}$/$\overline{\text{TA}}$/$\overline{\text{TS}}$/$\overline{\text{TEA}}$/$\overline{\text{DBG}}$/$\overline{\text{BG}}$/$\overline{\text{BR}}$	6	1
sp12	sp10	Data bus in normal mode	5	1
sp13	sp10	Data bus in ECC and PARITY modes	8	1
sp14	sp10	DP pins	8	1
sp14	sp10	All other pins	5	1

Note:

[1] Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.

Table 10 lists SIU output characteristics.

Table 10. AC Characteristics for SIU Outputs[1]

Spec Number		Characteristic	Max Delay (ns)	Min Delay (ns)
Max	Min		66 MHz	66 MHz
sp31	sp30	PSDVAL/TEA/TA	10	0.5
sp32	sp30	ADD/ADD_atr./BADDR/CI/GBL/WT	8	0.5
sp33a	sp30	Data bus	8	0.5
sp33b	sp30	DP	12	0.5
sp34	sp30	memc signals/ALE	6	0.5
sp35	sp30	all other signals	7.5	0.5

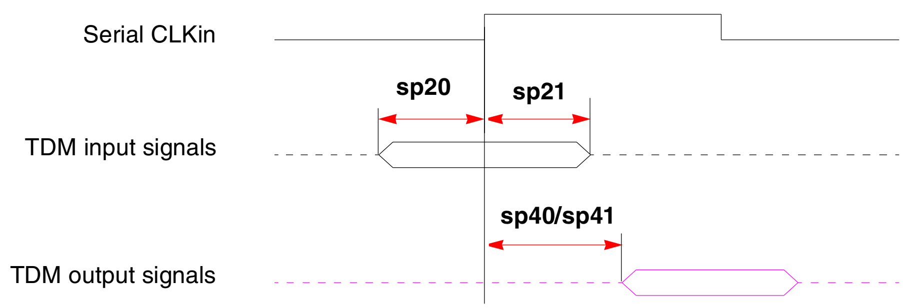
Note:

1 Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.

NOTE

Activating data pipelining (setting BR*x*[DR] in the memory controller) improves the AC timing. When data pipelining is activated, sp12 can be used for data bus setup even when ECC or PARITY are used. Also, sp33a can be used as the AC specification for DP signals.

Figure 8 shows TDM input and output signals.



Note: There are four possible TDM timing conditions:
1. Input sampled on the rising edge and output driven on the rising edge (shown).
2. Input sampled on the rising edge and output driven on the falling edge.
3. Input sampled on the falling edge and output driven on the falling edge.
4. Input sampled on the falling edge and output driven on the rising edge.

Figure 8. TDM Signal Diagram

Figure 9 shows the interaction of several bus signals.

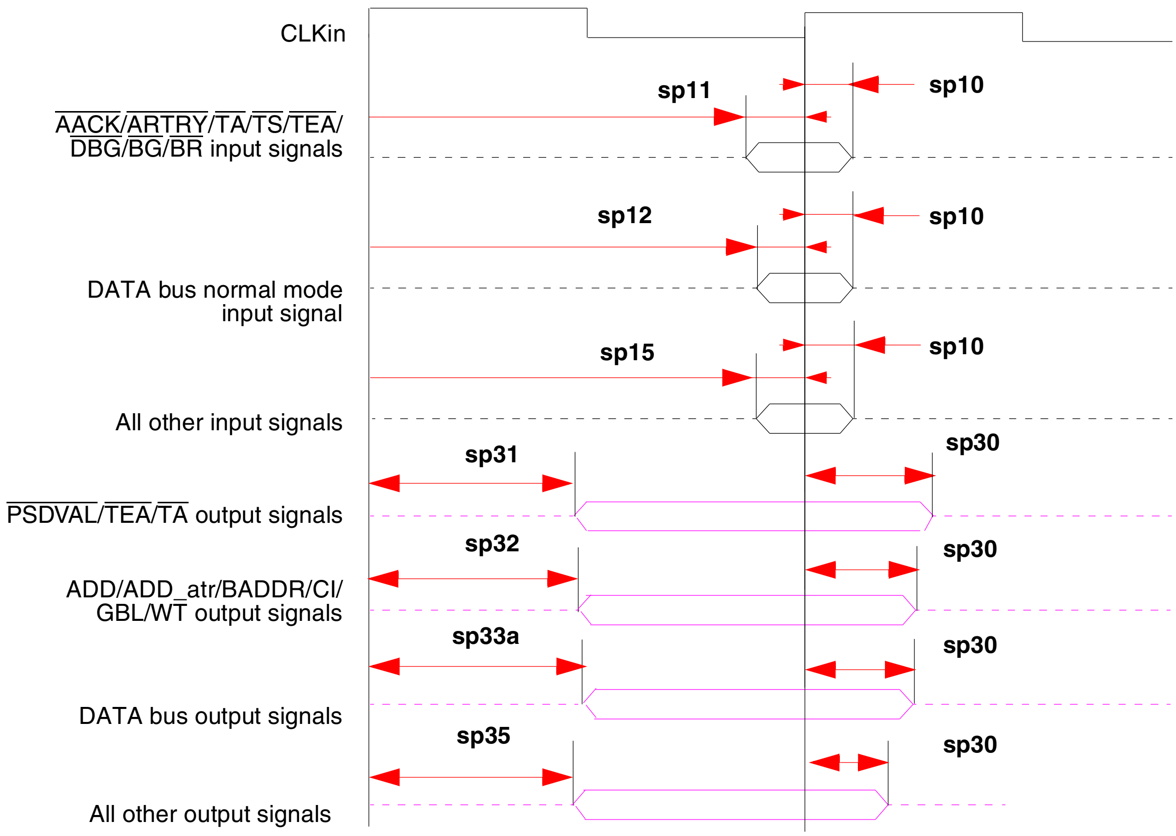


Figure 9. Bus Signals

Figure 10 shows signal behavior for all parity modes (including ECC, RMW parity, and standard parity).

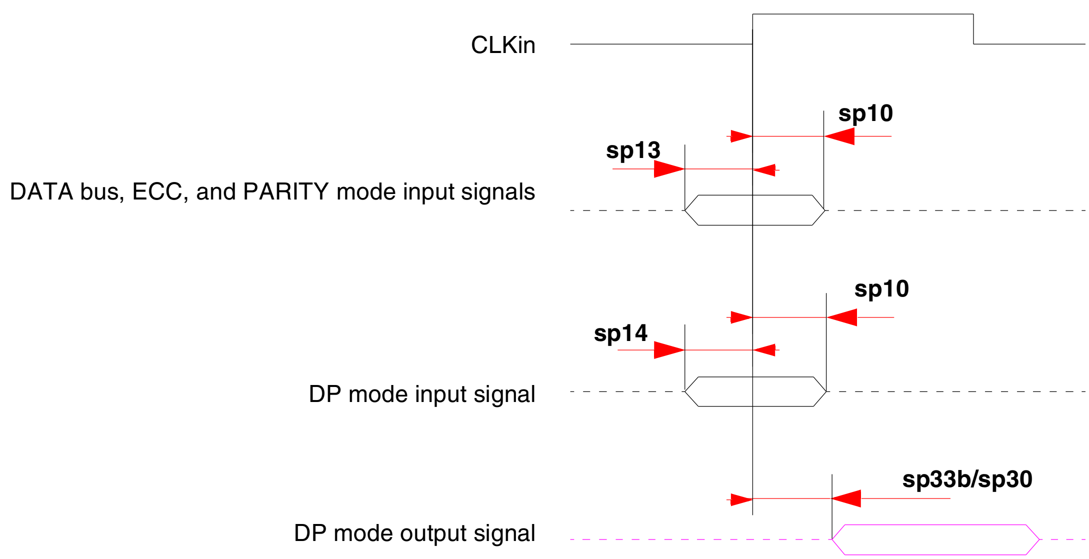


Figure 10. Parity Mode Diagram

Figure 11 shows signal behavior in MEMC mode.

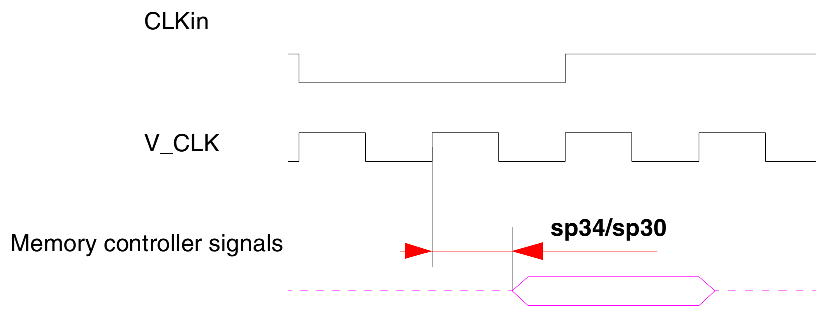


Figure 11. MEMC Mode Diagram

NOTE

Generally, all MPC8260 bus and system output signals are driven from the rising edge of the input clock (CLKin). Memory controller signals, however, trigger on four points within a CLKin cycle. Each cycle is divided by four internal ticks: T1, T2, T3, and T4. T1 always occurs at the rising edge, and T3 at the falling edge, of CLKin. However, the spacing of T2 and T4 depends on the PLL clock ratio selected, as shown in Table 11.

Table 11. Tick Spacing for Memory Controller Signals

PLL Clock Ratio	Tick Spacing (T1 Occurs at the Rising Edge of CLKin)		
	T2	T3	T4
1:2, 1:3, 1:4, 1:5, 1:6	1/4 CLKin	1/2 CLKin	3/4 CLKin
1:2.5	3/10 CLKin	1/2 CLKin	8/10 CLKin
1:3.5	4/14 CLKin	1/2 CLKin	11/14 CLKin

Figure 12 is a graphical representation of Table 11.

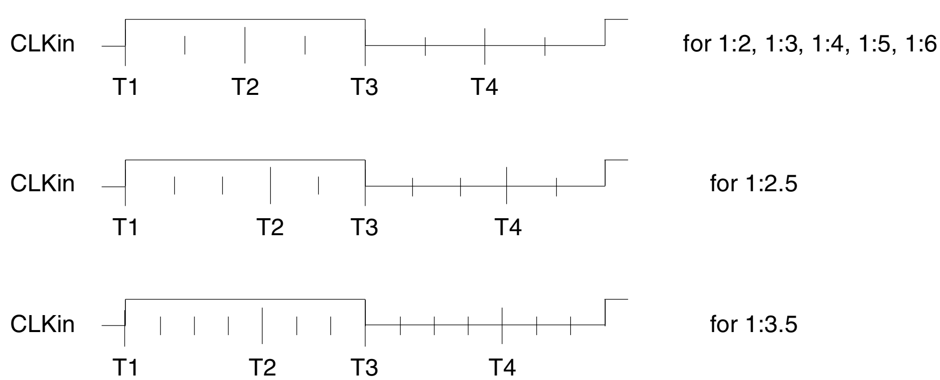


Figure 12. Internal Tick Spacing for Memory Controller Signals

NOTE

The UPM machine outputs change on the internal tick determined by the memory controller programming; the AC specifications are relative to the internal tick. Note that SDRAM and GPCM machine outputs change on CLKin's rising edge.

3 Clock Configuration Modes

To configure the main PLL multiplication factor and the core, CPM, and 60x bus frequencies, the MODCK[1–3] pins are sampled while $\overline{HRESET}$ is asserted. Table 12 shows the eight basic configuration modes. Another 49 modes are available by using the configuration pin ($\overline{RSTCONF}$) and driving four pins on the data bus.

NOTE

Clock configurations change only after $\overline{POR}$ is asserted.

3.1 Local Bus Mode

Table 12 describes default clock modes for the MPC8260.

Table 12. Clock Default Modes

MODCK[1–3]	Input Clock Frequency	CPM Multiplication Factor	CPM Frequency	Core Multiplication Factor	Core Frequency
000	33 MHz	3	100 MHz	4	133 MHz
001	33 MHz	3	100 MHz	5	166 MHz
010	33 MHz	4	133 MHz	4	133 MHz
011	33 MHz	4	133 MHz	5	166 MHz
100	66 MHz	2	133 MHz	2.5	166 MHz
101	66 MHz	2	133 MHz	3	200 MHz
110	66 MHz	2.5	166 MHz	2.5	166 MHz
111	66 MHz	2.5	166 MHz	3	200 MHz

Table 13 describes all possible clock configurations when using the hard reset configuration sequence. Note also that basic modes are shown in boldface type.

Table 13. Clock Configuration Modes[1]

MODCK_H–MODCK[1–3]	Input Clock Frequency[2,3,4]	CPM Multiplication Factor[2, 5]	CPM Frequency[2]	Core Multiplication Factor[2, 6]	Core Frequency[2]
0001_000	33 MHz	2	66 MHz	4	133 MHz
0001_001	33 MHz	2	66 MHz	5	166 MHz
0001_010	33 MHz	2	66 MHz	6	200 MHz
0001_011	33 MHz	2	66 MHz	7	233 MHz
0001_100	33 MHz	2	66 MHz	8	266 MHz

Table 13. Clock Configuration Modes[1] (continued)

MODCK_H–MODCK[1–3]	Input Clock Frequency[2,3,4]	CPM Multiplication Factor[2, 5]	CPM Frequency[2]	Core Multiplication Factor[2, 6]	Core Frequency[2]
0001_101	**33 MHz**	**3**	**100 MHz**	4	**133 MHz**
0001_110	**33 MHz**	**3**	**100 MHz**	5	**166 MHz**
0001_111	33 MHz	3	100 MHz	6	200 MHz
0010_000	33 MHz	3	100 MHz	7	233 MHz
0010_001	33 MHz	3	100 MHz	8	266 MHz
0010_010	**33 MHz**	**4**	**133 MHz**	**4**	**133 MHz**
0010_011	**33 MHz**	**4**	**133 MHz**	**5**	**166 MHz**
0010_100	33 MHz	4	133 MHz	6	200 MHz
0010_101	33 MHz	4	133 MHz	7	233 MHz
0010_110	33 MHz	4	133 MHz	8	266 MHz
0010_111	33 MHz	5	166 MHz	4	133 MHz
0011_000	33 MHz	5	166 MHz	5	166 MHz
0011_001	33 MHz	5	166 MHz	6	200 MHz
0011_010	33 MHz	5	166 MHz	7	233 MHz
0011_011	33 MHz	5	166 MHz	8	266 MHz
0011_100	33 MHz	6	200 MHz	4	133 MHz
0011_101	33 MHz	6	200 MHz	5	166 MHz
0011_110	33 MHz	6	200 MHz	6	200 MHz
0011_111	33 MHz	6	200 MHz	7	233 MHz
0100_000	33 MHz	6	200 MHz	8	266 MHz
0100_001	Reserved				
0100_010					
0100_011					
0100_100					
0100_101					
0100_110					

Table 13. Clock Configuration Modes[1] (continued)

MODCK_H–MODCK[1–3]	Input Clock Frequency[2,3,4]	CPM Multiplication Factor[2, 5]	CPM Frequency[2]	Core Multiplication Factor[2, 6]	Core Frequency[2]
0100_111	Reserved				
0101_000					
0101_001					
0101_010					
0101_011					
0101_100					
0101_101	66 MHz	2	133 MHz	2	133 MHz
0101_110	**66 MHz**	**2**	**133 MHz**	**2.5**	**166 MHz**
0101_111	**66 MHz**	**2**	**133 MHz**	**3**	**200 MHz**
0110_000	66 MHz	2	133 MHz	3.5	233 MHz
0110_001	66 MHz	2	133 MHz	4	266 MHz
0110_010	66 MHz	2	133 MHz	4.5	300 MHz
0110_011	66 MHz	2.5	166 MHz	2	133 MHz
0110_100	**66 MHz**	**2.5**	**166 MHz**	**2.5**	**166 MHz**
0110_101	**66 MHz**	**2.5**	**166 MHz**	**3**	**200 MHz**
0110_110	66 MHz	2.5	166 MHz	3.5	233 MHz
0110_111	66 MHz	2.5	166 MHz	4	266 MHz
0111_000	66 MHz	2.5	166 MHz	4.5	300 MHz
0111_001	66 MHz	3	200 MHz	2	133 MHz
0111_010	66 MHz	3	200 MHz	2.5	166 MHz
0111_011	66 MHz	3	200 MHz	3	200 MHz
0111_100	66 MHz	3	200 MHz	3.5	233 MHz
0111_101	66 MHz	3	200 MHz	4	266 MHz
0111_110	66 MHz	3	200 MHz	4.5	300 MHz
0111_111	66 MHz	3.5	233 MHz	2	133 MHz
1000_000	66 MHz	3.5	233 MHz	2.5	166 MHz
1000_001	66 MHz	3.5	233 MHz	3	200 MHz
1000_010	66 MHz	3.5	233 MHz	3.5	233 MHz
1000_011	66 MHz	3.5	233 MHz	4	266 MHz
1000_100	66 MHz	3.5	233 MHz	4.5	300 MHz

Note:

[1] Because of speed dependencies, not all of the possible configurations in Table 13 are applicable.
[2] The user should choose the input clock frequency and the multiplication factors such that the frequency of the CPU ranges between 133–200 and the CPM ranges between 50–166 MHz.
[3] Input clock frequency is given only for the purpose of reference. User should set MODCK_H–MODCK_L so that the resulting configuration does not exceed the frequency rating of the user's part.
[4] 60x and local bus frequency. Identical to CLKIN.
[5] CPM multiplication factor = CPM clock/bus clock
[6] CPU multiplication factor = Core PLL multiplication factor

4 Pinout

This section provides the pin assignments and pinout list for the MPC8260.

4.1 Pin Assignments

Figure 13 shows the pinout of the MPC8260 480 TBGA package as viewed from the top surface.

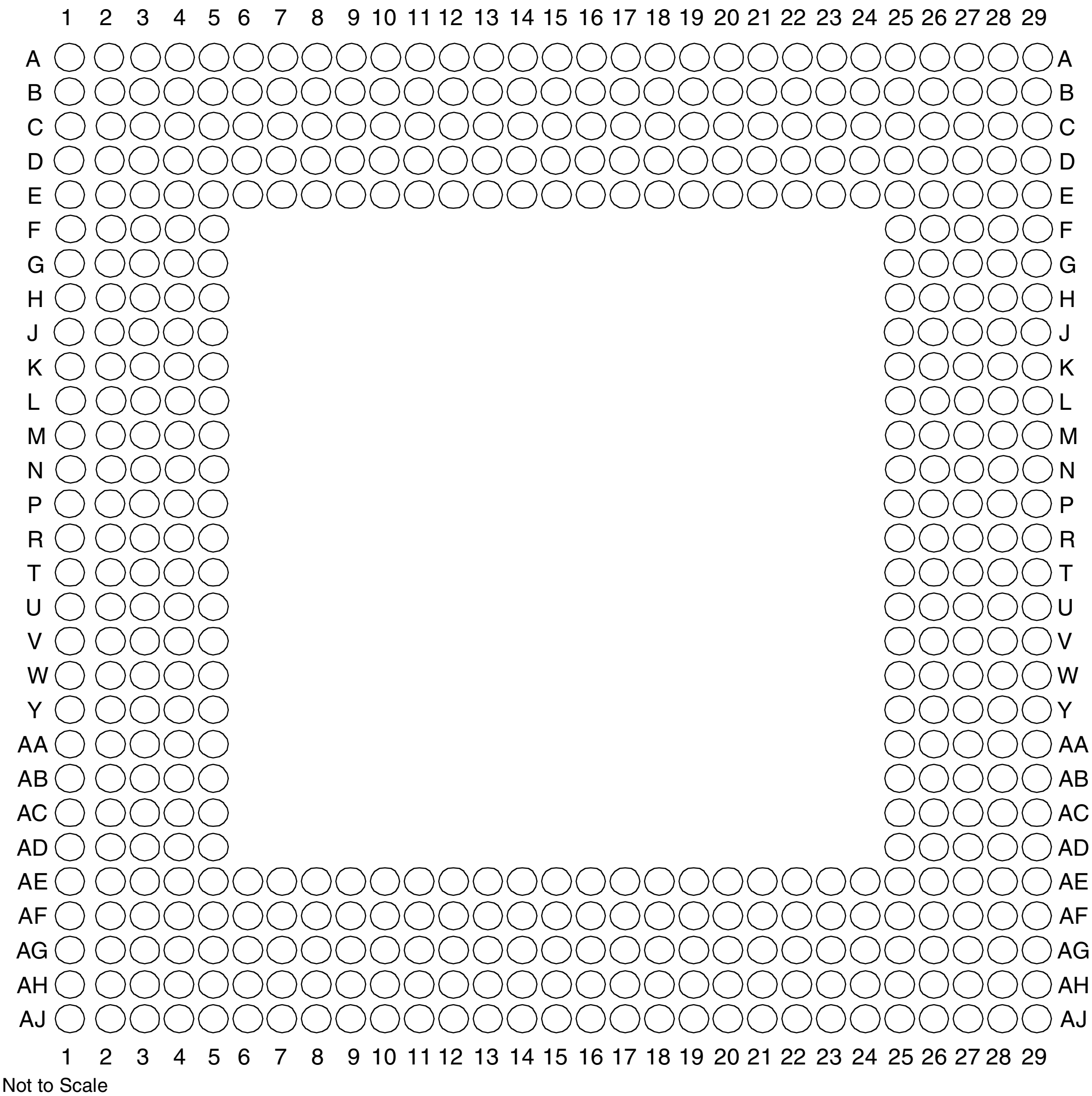


Figure 13. Pinout of the 480 TBGA Package as Viewed from the Top Surface

Figure 14 shows the side profile of the TBGA package to indicate the direction of the top surface view.

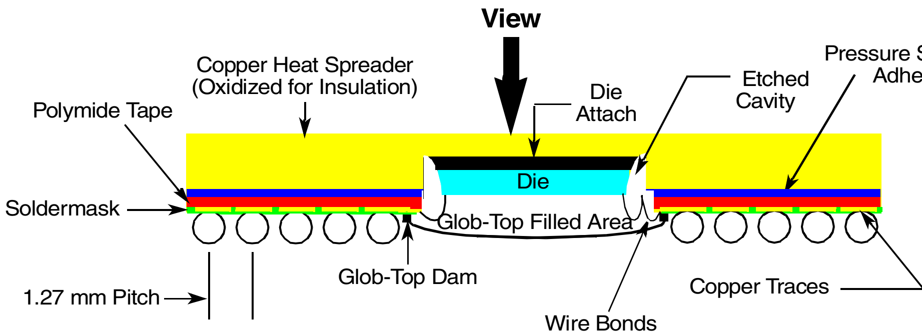


Figure 14. Side View of the TBGA Package

Table 14 shows the pinout list of the MPC8260. Table 15 defines conventions and acronyms used in Table 14.

Table 14. Pinout List

Pin Name	Ball
$\overline{BR}$	W5
$\overline{BG}$	F4
$\overline{ABB}/\overline{IRQ2}$	E2
$\overline{TS}$	E3
A0	G1
A1	H5
A2	H2
A3	H1
A4	J5
A5	J4
A6	J3
A7	J2
A8	J1
A9	K4
A10	K3
A11	K2
A12	K1
A13	L5
A14	L4
A15	L3
A16	L2
A17	L1